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### **Understanding Embedded - FPGAs (Field Programmable Gate Array)**

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

### **Applications of Embedded - FPGAs**

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications,

#### **Details**

Product Status	Active
Number of LABs/CLBs	-
Number of Logic Elements/Cells	300000
Total RAM Bits	21094400
Number of I/O	388
Number of Gates	-
Voltage - Supply	0.97V ~ 1.08V
Mounting Type	Surface Mount
Operating Temperature	-40°C ~ 100°C (TJ)
Package / Case	784-BBGA, FCBGA
Supplier Device Package	784-FCBGA (29x29)
Purchase URL	<a href="https://www.e-xfl.com/product-detail/microchip-technology/mpf300ts-1fcg784i">https://www.e-xfl.com/product-detail/microchip-technology/mpf300ts-1fcg784i</a>

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**Table 8 • Maximum Overshoot During Transitions for GPIO**

AC ( $V_{IN}$ ) Overshoot Duration as % at $T_J = 100^\circ C$	Condition (V)
100	3.8
100	3.85
100	3.9
100	3.95
70	4
50	4.05
33	4.1
22	4.15
14	4.2
9.8	4.25
6.5	4.3
4.4	4.35
3	4.4
2	4.45
1.4	4.5
0.9	4.55
0.6	4.6

**Note:** Overshoot level is for  $V_{DDI}$  at 3.3 V.

The following table shows the maximum AC input voltage ( $V_{IN}$ ) undershoot duration for GPIO.

**Table 9 • Maximum Undershoot During Transitions for GPIO**

AC ( $V_{IN}$ ) Undershoot Duration as % at $T_J = 100^\circ C$	Condition (V)
100	-0.5
100	-0.55
100	-0.6
100	-0.65
100	-0.7
100	-0.75
100	-0.8
100	-0.85
100	-0.9
100	-0.95
100	-1
100	-1.05
100	-1.1
100	-1.15
100	-1.2
69	-1.25
45	-1.3

**Table 13 • DC Output Levels**

I/O Standard	V <sub>DDI</sub> Min (V)	V <sub>DDI</sub> Typ (V)	V <sub>DDI</sub> Max (V)	V <sub>OL</sub> Min (V)	V <sub>OL</sub> Max (V)	V <sub>OH</sub> Min (V)	V <sub>OH</sub> Max (V)	I <sub>OL<sup>2,6</sup></sub> mA	I <sub>OH<sup>2,6</sup></sub> mA
PCI <sup>1</sup>	3.15	3.3	3.45		0.1 x V <sub>DDI</sub>	0.9 x V <sub>DDI</sub>		1.5	0.5
LVTTL	3.15	3.3	3.45		0.4	2.4			
LVCMOS33	3.15	3.3	3.45		0.4	V <sub>DDI</sub> — 0.4			
LVCMOS25	2.375	2.5	2.625		0.4	V <sub>DDI</sub> — 0.4			
LVCMOS18	1.71	1.8	1.89		0.45	V <sub>DDI</sub> — 0.45			
LVCMOS15	1.425	1.5	1.575		0.25 x V <sub>DDI</sub>	0.75 x V <sub>DDI</sub>			
LVCMOS12	1.14	1.2	1.26		0.25 x V <sub>DDI</sub>	0.75 x V <sub>DDI</sub>			
SSTL25I <sup>3</sup>	2.375	2.5	2.625		V <sub>TT</sub> — 0.608	V <sub>TT</sub> + 0.608	8.1	8.1	
SSTL25II <sup>3</sup>	2.375	2.5	2.625		V <sub>TT</sub> — 0.810	V <sub>TT</sub> + 0.810	16.2	16.2	
SSTL18I <sup>3</sup>	1.71	1.8	1.89		V <sub>TT</sub> — 0.603	V <sub>TT</sub> + 0.603	6.7	6.7	
SSTL18II <sup>3</sup>	1.71	1.8	1.89		V <sub>TT</sub> — 0.603	V <sub>TT</sub> + 0.603	13.4	13.4	
SSTL15I <sup>4</sup>	1.425	1.5	1.575		0.2 x V <sub>DDI</sub>	0.8 x V <sub>DDI</sub>	V <sub>OL</sub> /40 (V <sub>DDI</sub> – V <sub>OH</sub> ) /40		
SSTL15II <sup>4</sup>	1.425	1.5	1.575		0.2 x V <sub>DDI</sub>	0.8 x V <sub>DDI</sub>	V <sub>OL</sub> /34 (V <sub>DDI</sub> – V <sub>OH</sub> ) /34		
SSTL135I <sup>4</sup>	1.283	1.35	1.418		0.2 x V <sub>DDI</sub>	0.8 x V <sub>DDI</sub>	V <sub>OL</sub> /40 (V <sub>DDI</sub> – V <sub>OH</sub> ) /40		
SSTL135II <sup>4</sup>	1.283	1.35	1.418		0.2 x V <sub>DDI</sub>	0.8 x V <sub>DDI</sub>	V <sub>OL</sub> /34 (V <sub>DDI</sub> – V <sub>OH</sub> ) /34		
HSTL15I	1.425	1.5	1.575		0.4	V <sub>DDI</sub> — 0.4	8	8	
HSTL15II	1.425	1.5	1.575		0.4	V <sub>DDI</sub> — 0.4	16	16	

I/O Standard	Bank Type	V <sub>O<sub>CM</sub></sub> <sup>1</sup> Min (V)	V <sub>O<sub>CM</sub></sub> Typ (V)	V <sub>O<sub>CM</sub></sub> Max (V)	V <sub>O<sub>D</sub></sub> <sup>2</sup> Min (V)	V <sub>O<sub>D</sub></sub> <sup>2</sup> Typ (V)	V <sub>O<sub>D</sub></sub> <sup>2</sup> Max (V)
MILVDS25 <sup>3</sup>	GPIO		1.25		0.396	0.442	0.453
LVPECLE33 <sup>3</sup>	GPIO		1.65		0.664	0.722	0.755
MIPIE25 <sup>3</sup>	GPIO		0.25		0.1	0.22	0.3

1. V<sub>O<sub>CM</sub></sub> is the output common mode voltage.
2. V<sub>O<sub>D</sub></sub> is the output differential voltage.
3. Emulated output only.

### 6.3.3 Complementary Differential DC Input and Output Levels

The following tables list the complementary differential DC I/O levels.

**Table 16 • Complementary Differential DC Input Levels**

I/O Standard	V <sub>DDI</sub> Min (V)	V <sub>DDI</sub> Typ (V)	V <sub>DDI</sub> Max (V)	V <sub>I<sub>CM</sub></sub> <sup>1,3</sup> Min (V)	V <sub>I<sub>CM</sub></sub> <sup>1,3</sup> Typ (V)	V <sub>I<sub>CM</sub></sub> <sup>1,3</sup> Max (V)	V <sub>I<sub>D</sub></sub> <sup>2</sup> Min (V)	V <sub>I<sub>D</sub></sub> Max (V)
SSTL25I	2.375	2.5	2.625	1.164	1.250	1.339	0.1	
SSTL25II	2.375	2.5	2.625	1.164	1.250	1.339	0.1	
SSTL18I	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
SSTL18II	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
SSTL15I	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
SSTL15II	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
SSTL135I	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
SSTL135II	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
HSTL15I	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
HSTL15II	1.425	1.5	1.575	0.698	0.750	0.803	0.1	
HSTL135I	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
HSTL135II	1.283	1.35	1.418	0.629	0.675	0.723	0.1	
HSTL12I	1.14	1.2	1.26	0.559	0.600	0.643	0.1	
HSUL18I	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
HSUL18II	1.71	1.8	1.89	0.838	0.900	0.964	0.1	
HSUL12I	1.14	1.2	1.26	0.559	0.600	0.643	0.1	
POD12I	1.14	1.2	1.26	0.787	0.840	0.895	0.1	
POD12II	1.14	1.2	1.26	0.787	0.840	0.895	0.1	

1. V<sub>I<sub>CM</sub></sub> is the input common mode voltage.
2. V<sub>I<sub>D</sub></sub> is the input differential voltage.
3. V<sub>I<sub>CM</sub></sub> rules are as follows:
  - a. V<sub>I<sub>CM</sub></sub> must be less than V<sub>DDI</sub> - 0.4V;
  - b. V<sub>I<sub>CM</sub></sub> + V<sub>I<sub>D</sub></sub>/2 must be < V<sub>DDI</sub> + 0.4 V;
  - c. V<sub>I<sub>CM</sub></sub> - V<sub>I<sub>D</sub></sub>/2 must be > V<sub>SS</sub> - 0.3 V.

**Table 17 • Complementary Differential DC Output Levels**

I/O Standard	V <sub>DDI</sub> Min (V)	V <sub>DDI</sub> Typ (V)	V <sub>DDI</sub> Max (V)	V <sub>OL</sub> Min (V)	V <sub>OL</sub> Max (V)	V <sub>OH</sub> <sup>1,3</sup> Min (V)	I <sub>OL</sub> <sup>2</sup> Min (mA)	I <sub>OH</sub> <sup>2</sup> Min (mA)
SSTL25I	2.375	2.5	2.625		V <sub>TT</sub> – 0.608	V <sub>TT</sub> + 0.608	8.1	8.1
SSTL25II	2.375	2.5	2.625		V <sub>TT</sub> – 0.810	V <sub>TT</sub> + 0.810	16.2	16.2
SSTL18I	1.71	1.8	1.89		V <sub>TT</sub> – 0.603	V <sub>TT</sub> + 0.603	6.7	6.7
SSTL18II	1.71	1.8	1.89		V <sub>TT</sub> – 0.603	V <sub>TT</sub> + 0.603	13.4	13.4
SSTL15I <sup>4</sup>	1.425	1.5	1.575		0.2 × V <sub>DDI</sub>	0.8 × V <sub>DDI</sub>	V <sub>OL</sub> /40	(V <sub>DDI</sub> – V <sub>OH</sub> )/40
SSTL15II <sup>4</sup>	1.425	1.5	1.575		0.2 × V <sub>DDI</sub>	0.8 × V <sub>DDI</sub>	V <sub>OL</sub> /34	(V <sub>DDI</sub> – V <sub>OH</sub> )/34
SSTL135I <sup>4</sup>	1.283	1.35	1.418		0.2 × V <sub>DDI</sub>	0.8 × V <sub>DDI</sub>	V <sub>OL</sub> /40	(V <sub>DDI</sub> – V <sub>OH</sub> )/40
SSTL135II <sup>4</sup>	1.283	1.35	1.418		0.2 × V <sub>DDI</sub>	0.8 × V <sub>DDI</sub>	V <sub>OL</sub> /34	(V <sub>DDI</sub> – V <sub>OH</sub> )/34
HSTL15I	1.425	1.5	1.575		0.4	V <sub>DDI</sub> – 0.4	8	8
HSTL15II	1.425	1.5	1.575		0.4	V <sub>DDI</sub> – 0.4	16	16
HSTL135I <sup>4</sup>	1.283	1.35	1.418		0.2 × V <sub>DDI</sub>	0.8 × V <sub>DDI</sub>	V <sub>OL</sub> /50	(V <sub>DDI</sub> – V <sub>OH</sub> )/50
HSTL135II <sup>4</sup>	1.283	1.35	1.418		0.2 × V <sub>DDI</sub>	0.8 × V <sub>DDI</sub>	V <sub>OL</sub> /25	(V <sub>DDI</sub> – V <sub>OH</sub> )/25
HSTL12I <sup>4</sup>	1.14	1.2	1.26		0.1 × V <sub>DDI</sub>	0.9 × V <sub>DDI</sub>	V <sub>OL</sub> /50	(V <sub>DDI</sub> – V <sub>OH</sub> )/50
HSUL18I <sup>4</sup>	1.71	1.8	1.89		0.1 × V <sub>DDI</sub>	0.9 × V <sub>DDI</sub>	V <sub>OL</sub> /55	(V <sub>DDI</sub> – V <sub>OH</sub> )/55
HSUL18II <sup>4</sup>	1.71	1.8	1.89		0.1 × V <sub>DDI</sub>	0.9 × V <sub>DDI</sub>	V <sub>OL</sub> /25	(V <sub>DDI</sub> – V <sub>OH</sub> )/25
HSUL12I <sup>4</sup>	1.14	1.2	1.26		0.1 × V <sub>DDI</sub>	0.9 × V <sub>DDI</sub>	V <sub>OL</sub> /40	(V <sub>DDI</sub> – V <sub>OH</sub> )/40
POD12I <sup>3,4</sup>	1.14	1.2	1.26		0.5 × V <sub>DDI</sub>		V <sub>OL</sub> /48	(V <sub>DDI</sub> – V <sub>OH</sub> )/48
POD12II <sup>3,4</sup>	1.14	1.2	1.26		0.5 × V <sub>DDI</sub>		V <sub>OL</sub> /34	(V <sub>DDI</sub> – V <sub>OH</sub> )/34

1. V<sub>OH</sub> is the single-ended high-output voltage.
2. The total DC sink/source current of all IOs within a lane is limited as follows:
  - a. HSIO lane: 120 mA per 12 IO buffers.
  - b. GPIO lane: 160 mA per 12 IO buffers
3. V<sub>OH\_MAX</sub> based on external pull-up termination (pseudo-open drain).
4. I<sub>OL</sub>/I<sub>OH</sub> units for impedance standards in amps (not mA).

### 6.3.4 HSIO On-Die Termination

The following tables lists the on-die termination calibration accuracy specifications for HSIO bank.

**Table 18 • Single-Ended Thevenin Termination (Internal Parallel Thevenin Termination)**

Min (%)	Typ	Max (%)	Unit	Condition
-40	50	20	Ω	V <sub>DDI</sub> = 1.8 V/1.5 V/1.35 V/1.2 V
-40	75	20	Ω	V <sub>DDI</sub> = 1.8 V
-40	150	20	Ω	V <sub>DDI</sub> = 1.8 V
-20	20	20	Ω	V <sub>DDI</sub> = 1.5 V/1.35 V
-20	30	20	Ω	V <sub>DDI</sub> = 1.5 V/1.35 V
-20	40	20	Ω	V <sub>DDI</sub> = 1.5 V/1.35 V
-20	60	20	Ω	V <sub>DDI</sub> = 1.5 V/1.35 V
-20	120	20	Ω	V <sub>DDI</sub> = 1.5 V/1.35 V

Standard	Description	V <sub>L</sub> <sup>1</sup>	V <sub>H</sub> <sup>1</sup>	V <sub>ID</sub> <sup>2</sup>	V <sub>ICM</sub> <sup>2</sup>	V <sub>MEAS</sub> <sup>3, 4</sup>	V <sub>REF</sub> <sup>1, 5</sup>	Unit
HSTL135II	Differential HSTL 1.35 V Class II	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.675	0		V
HSTL12	Differential HSTL 1.2 V	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.600	0		V
HSUL18I	Differential HSUL 1.8 V Class I	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.900	0		V
HSUL18II	Differential HSUL 1.8 V Class II	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.900	0		V
HSUL12	Differential HSUL 1.2 V	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.600	0		V
POD12I	Differential POD 1.2 V Class I	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.600	0		V
POD12II	Differential POD 1.2 V Class II	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.600	0		V
MIPI25	Mobile Industry Processor Interface	V <sub>ICM</sub> – .125	V <sub>ICM</sub> + .125	0.250	0.200	0		V

1. Measurements are made at typical, minimum, and maximum V<sub>REF</sub> values. Reported delays reflect worst-case of these measurements. V<sub>REF</sub> values listed are typical. Input waveform switches between V<sub>L</sub> and V<sub>H</sub>. All rise and fall times must be 1 V/ns.
2. Differential receiver standards all use 250 mV V<sub>ID</sub> for timing. V<sub>CM</sub> is different between different standards.
3. Input voltage level from which measurement starts.
4. The value given is the differential input voltage.
5. This is an input voltage reference that bears no relation to the V<sub>REF</sub>/V<sub>MEAS</sub> parameters found in IBIS models or shown in [Output Delay Measurement—Single-Ended Test Setup \(see page 27\)](#).
6. Emulated bi-directional interface.

## 7.1.2 Output Delay Measurement Methodology

The following section provides information about the methodology for output delay measurement.

**Table 23 • Output Delay Measurement Methodology**

Standard	Description	R <sub>REF</sub> (Ω)	C <sub>REF</sub> (pF)	V <sub>MEAS</sub> (V)	V <sub>REF</sub> (V)
PCI	PCIE 3.3 V	25	10	1.65	
LVTTL33	LVTTL 3.3 V	1M	0	1.65	
LVCMOS33	LVCMOS 3.3 V	1M	0	1.65	
LVCMOS25	LVCMOS 2.5 V	1M	0	1.25	
LVCMOS18	LVCMOS 1.8 V	1M	0	0.90	
LVCMOS15	LVCMOS 1.5 V	1M	0	0.75	
LVCMOS12	LVCMOS 1.2 V	1M	0	0.60	
SSTL25I	Stub-series terminated logic 2.5 V Class I	50	0	V <sub>REF</sub>	1.25
SSTL25II	SSTL 2.5 V Class II	50	0	V <sub>REF</sub>	1.25

Parameter	Interface Name	Topology	STD Min	STD Typ	STD Max	-1 Min	-1 Typ	-1 Max	Unit	Forwarded Clock-to-Data Skew
Output $F_{MAX}$ 2:1	TX_DDRX_B_C	Tx DDR digital mode							MHz	From a HS_IO_CLK clock source, centered with PLL
Output $F_{MAX}$ 4:1	TX_DDRX_B_C	Tx DDR digital mode							MHz	From a HS_IO_CLK clock source, centered with PLL
Output $F_{MAX}$ 8:1	TX_DDRX_B_C	Tx DDR digital mode							MHz	From a HS_IO_CLK clock source, centered with PLL
In delay, out delay, DLL delay step sizes			12.7	30	35	12.7	25	29.5	ps	

**Table 34 • I/O CDR Switching Characteristics**

Parameter	Min	Max	Unit
Data rate	266	1250	Mbps
Receiver Sinusoidal jitter tolerance <sup>1</sup>	0.2		UI

1. Jitter values based on bit error ratio (BER) of 10–12, 80 MHz sinusoidal jitter injected to Rx data.

**Note:** See the LVDS output buffer specifications for transmit characteristics.

## 7.2 Clocking Specifications

This section describes the PLL and DLL clocking and oscillator specifications.

### 7.2.1 Clocking

The following table provides clocking specifications.

**Table 35 • Global and Regional Clock Characteristics (−40 °C to 100 °C)**

Parameter	Symbol	V <sub>DD</sub> = 1.0 V STD	V <sub>DD</sub> = 1.0 V –1	V <sub>DD</sub> = 1.05 V STD	V <sub>DD</sub> = 1.05 V –1	Unit	Condition
Global clock $F_{MAXG}$		500	500	500	500	MHz	
Regional clock $F_{MAXR}$	$F_{MAXR}$	375	375	375	375	MHz	Transceiver interfaces only
	$F_{MAXR}$	250	250	250	250	MHz	All other interfaces
Global clock duty cycle distortion	$T_{DCDG}$	190	190	190	190	ps	At 500 MHz

Parameter	Symbol	V <sub>DD</sub> = 1.0 V STD	V <sub>DD</sub> = 1.0 V –1	V <sub>DD</sub> = 1.05 V STD	V <sub>DD</sub> = 1.05 V –1	Unit	Condition
Regional clock duty cycle distortion	T <sub>DCDR</sub>	120	120	120	120	ps	At 250 MHz

The following table provides clocking specifications from –40 °C to 100 °C.

**Table 36 • High-Speed I/O Clock Characteristics (–40 °C to 100 °C)**

Parameter	Symbol	V <sub>DD</sub> = 1.0 V STD	V <sub>DD</sub> = 1.0 V –1	V <sub>DD</sub> = 1.05 V STD	V <sub>DD</sub> = 1.05 V –1	Unit	Condition
High-speed I/O clock F <sub>MAX</sub>	F <sub>MAXB</sub>	1000	1250	1000	1250	MHz	HSIO and GPIO
High-speed I/O clock skew <sup>1</sup>	F <sub>SKEWB</sub>	30	20	30	20	ps	HSIO without bridging
	F <sub>SKEWB</sub>	600	500	600	500	ps	HSIO with bridging
	F <sub>SKEWB</sub>	45	35	45	35	ps	GPIO without bridging
	F <sub>SKEWB</sub>	75	60	75	60	ps	GPIO with bridging
High-speed I/O clock duty cycle distortion <sup>2</sup>	T <sub>DCB</sub>	90	90	90	90	ps	HSIO without bridging
	T <sub>DCB</sub>	115	115	115	115	ps	HSIO with bridging
	T <sub>DCB</sub>	90	90	90	90	ps	GPIO without bridging
	T <sub>DCB</sub>	115	115	115	115	ps	GPIO with bridging

1. F<sub>SKEWB</sub> is the worst-case clock-tree skew observable between sequential I/O elements. Clock-tree skew is significantly smaller at I/O registers close to each other and fed by the same or adjacent clock-tree branches. Use the Microsemi Timing Analyzer tool to evaluate clock skew specific to the design.
2. Parameters listed in this table correspond to the worst-case duty cycle distortion observable at the I/O flip flops. IBIS should be used to calculate any additional duty cycle distortion that might be caused by asymmetrical rise/fall times for any I/O standard.

## 7.2.2 PLL

The following table provides information about PLL.

**Table 37 • PLL Electrical Characteristics**

Parameter	Symbol	Min	Typ	Max	Unit
Input clock frequency (integer mode)	F <sub>INI</sub>	1		1250	MHz
Input clock frequency (fractional mode)	F <sub>INF</sub>	10		1250	MHz
Minimum reference or feedback pulse width <sup>1</sup>	F <sub>INPULSE</sub>	200			ps
Frequency at the Frequency Phase Detector (PFD) (integer mode)	F <sub>PHDETI</sub>	1		312	MHz
Frequency at the PFD (fractional mode)	F <sub>PHDETF</sub>	10	50	125	MHz
Allowable input duty cycle	F <sub>INDUTY</sub>	25		75	%

### 7.3.2 SRAM Blocks

The following tables describe the LSRAM blocks' performance.

**Table 43 • LSRAM Performance Industrial Temperature Range (−40 °C to 100 °C)**

Parameter	V <sub>DD</sub> = 1.0 V – STD	V <sub>DD</sub> = 1.0 V – 1	V <sub>DD</sub> = 1.05 V – STD	V <sub>DD</sub> = 1.05 V – 1	Unit	Condition
Operating frequency	343	428	343	428	MHz	Two-port, all supported widths, pipelined, simple-write, and write-feed-through
	309	428	309	428	MHz	Two-port, all supported widths, non-pipelined, simple-write, and write-feed-through
	343	428	343	428	MHz	Dual-port, all supported widths, pipelined, simple-write, and write-feed-through
	309	428	309	428	MHz	Dual-port, all supported widths, non-pipelined, simple-write, and write-feed-through
	343	428	343	428	MHz	Two-port pipelined ECC mode, pipelined, simple-write, and write-feed-through
	279	295	279	295	MHz	Two-port non-pipelined ECC mode, pipelined, simple-write, and write-feed-through
	343	428	343	428	MHz	Two-port pipelined ECC mode, non-pipelined, simple-write, and write-feed-through
	196	285	196	285	MHz	Two-port non-pipelined ECC mode, non-pipelined, simple-write, and write-feed-through
	274	285	274	285	MHz	Two-port, all supported widths, pipelined, and read-before-write
	274	285	274	285	MHz	Two-port, all supported widths, non-pipelined, and read-before-write
	274	285	274	285	MHz	Dual-port, all supported widths, pipelined, and read-before-write
	274	285	274	285	MHz	Dual-port, all supported widths, non-pipelined, and read-before-write
	274	285	274	285	MHz	Two-port pipelined ECC mode, pipelined, and read-before-write
	274	285	274	285	MHz	Two-port non-pipelined ECC mode, pipelined, and read-before-write
	274	285	274	285	MHz	Two-port pipelined ECC mode, non-pipelined, and read-before-write
	193	285	193	285	MHz	Two-port non-pipelined ECC mode, non-pipelined, and read-before-write

**Table 44 • μSRAM Performance**

Parameter	Symbol	V <sub>DD</sub> = 1.0 V – STD	V <sub>DD</sub> = 1.0 V – 1	V <sub>DD</sub> = 1.05 V – STD	V <sub>DD</sub> = 1.05 V – 1	Unit	Condition
Operating frequency	F <sub>MAX</sub>	400	415	450	480	MHz	Write-port
Read access time	T <sub>AC</sub>		2		2	ns	Read-port

**Table 45 • μPROM Performance**

Parameter	Symbol	V <sub>DD</sub> = 1.0 V – STD	V <sub>DD</sub> = 1.0 V – 1	V <sub>DD</sub> = 1.05 V – STD	V <sub>DD</sub> = 1.05 V – 1	Unit
Read access time	T <sub>AC</sub>	10	10	10	10	ns

## 7.4

### Transceiver Switching Characteristics

This section describes transceiver switching characteristics.

#### 7.4.1

##### Transceiver Performance

The following table describes transceiver performance.

**Table 46 • PolarFire Transceiver and TXPLL Performance**

Parameter	Symbol	STD Min	STD Typ	STD Max	-1 Min	-1 Typ	-1 Max	Unit
Tx data rate <sup>1,2</sup>	F <sub>TXRate</sub>	0.25		10.3125	0.25		12.7	Gbps
Tx OOB (serializer bypass) data rate	F <sub>TXRateOOB</sub>	DC		1.5	DC		1.5	Gbps
Rx data rate when AC coupled <sup>2</sup>	F <sub>RxRateAC</sub>	0.25		10.3125	0.25		12.7	Gbps
Rx data rate when DC coupled	F <sub>RxRateDC</sub>	0.25		3.2	0.25		3.2	Gbps
Rx OOB (deserializer bypass) data rate	F <sub>TXRateOOB</sub>	DC		1.25	DC		1.25	Gbps
TXPLL output frequency <sup>3</sup>	F <sub>TXPLL</sub>	1.6		6.35	1.6		6.35	GHz
Rx CDR mode	F <sub>RXCDR</sub>	0.25		10.3125	0.25		10.3125	Gbps
Rx DFE mode <sup>2</sup>	F <sub>RXDDE</sub>	3.0		10.3125	3.0		12.7	Gbps
Rx Eye Monitor mode <sup>2</sup>	F <sub>RXEyeMon</sub>	3.0		10.3125	3.0		12.7	Gbps

1. The reference clock is required to be a minimum of 75 MHz for data rates of 10 Gbps and above.
2. For data rates greater than 10.3125 Gbps, VDDA must be set to 1.05 V mode. See supply tolerance in the section [Recommended Operating Conditions \(see page 6\)](#).
3. The Tx PLL rate is between 0.5x to 5.5x the Tx data rate. The Tx data rate depends on per XCVR lane Tx post-divider settings.

#### 7.4.2

##### Transceiver Reference Clock Performance

The following table describes performance of the transceiver reference clock.

**Table 47 • PolarFire Transceiver Reference Clock AC Requirements**

Parameter	Symbol	STD Min	STD Typ	STD Max	-1 Min	-1 Typ	-1 Max	Unit
Reference clock input rate <sup>1,2</sup>	F <sub>TXREFCLK</sub>	20		800	20		800	MHz

5. Improved jitter characteristics for a specific industry standard are possible in many cases due to improved reference clock or higher V<sub>CO</sub> rate used.
6. Tx jitter is specified with all transmitters on the device enabled, a 10–12-bit error rate (BER) and Tx data pattern of PRBS7.
7. From the PMA mode, the TX\_ELEC\_IDLE port to the XVCN TXP/N pins.  
FTxRefClk = 75 MHz with typical settings.  
For data rates greater than 10.3125 Gbps, VDDA must be set to 1.05 V mode. See supply tolerance in the section [Recommended Operating Conditions \(see page 6\)](#). (see page 6)

## 7.4.6 Receiver Performance

The following table describes performance of the receiver.

**Table 53 • PolarFire Transceiver Receiver Characteristics**

Parameter	Symbol	Min	Typ	Max	Unit	Condition
Input voltage range	V <sub>IN</sub>	0		V <sub>DDA</sub> + 0.3	V	
Differential peak-to-peak amplitude	V <sub>IDPP</sub>	140		1250	mV	
Differential termination	V <sub>ITERM</sub>	85			Ω	
	V <sub>ITERM</sub>	100			Ω	
	V <sub>ITERM</sub>	150			Ω	
Common mode voltage	V <sub>ICMDC</sub> <sup>1</sup>	0.7 × V <sub>DDA</sub>		0.9 × V <sub>DDA</sub>	V	DC coupled
Exit electrical idle detection time	T <sub>EIDET</sub>	50	100		ns	
Run length of consecutive identical digits (CID)	C <sub>ID</sub>		200		UI	
CDR PPM tolerance <sup>2</sup>	C <sub>DRPPM</sub>		1.15		% UI	
CDR lock-to-data time	T <sub>LTD</sub>				CDR <sub>REFCLK</sub>	
					UI	
CDR lock-to-ref time	T <sub>LTF</sub>				CDR <sub>REFCLK</sub>	
					UI	
Loss-of-signal detect (Peak Detect Range setting = high) <sup>9</sup>	V <sub>DETLHIGH</sub>				mV	Setting = 1
	V <sub>DETLHIGH</sub>				mV	Setting = 2
	V <sub>DETLHIGH</sub>				mV	Setting = 3
	V <sub>DETLHIGH</sub>				mV	Setting = 4
	V <sub>DETLHIGH</sub>				mV	Setting = 5
	V <sub>DETLHIGH</sub>				mV	Setting = 6
	V <sub>DETLHIGH</sub>				mV	Setting = 7
Loss-of-signal detect (Peak Detect Range setting = low) <sup>9</sup>	V <sub>DETLOW</sub>	65	175		mV	Setting = PCIe <sup>3,7</sup>
	V <sub>DETLOW</sub>	95	190		mV	Setting = SATA <sup>4,8</sup>
	V <sub>DETLOW</sub>	75	170		mV	Setting = 1
	V <sub>DETLOW</sub>	95	185		mV	Setting = 2
	V <sub>DETLOW</sub>	100	190		mV	Setting = 3
	V <sub>DETLOW</sub>	140	210		mV	Setting = 4
	V <sub>DETLOW</sub>	155	240		mV	Setting = 5
	V <sub>DETLOW</sub>	165	245		mV	Setting = 6
	V <sub>DETLOW</sub>	170	250		mV	Setting = 7
Sinusoidal jitter tolerance	T <sub>SJTOL</sub>				UI	>8.5 Gbps – 12.7 Gbps <sup>5,10</sup>

## 7.5.7 CPRI

The following table describes CPRI.

**Table 66 • CPRI**

	Data Rate	Min	Max	Unit
Total transmit jitter	0.6144 Gbps			UI
	1.2288 Gbps			UI
	2.4576 Gbps			UI
	3.0720 Gbps			UI
	4.9152 Gbps			UI
	6.1440 Gbps			UI
	9.8304 Gbps			UI
	10.1376 Gbps			UI
	12.16512 Gbps <sup>1</sup>			UI
Receive jitter tolerance	0.6144 Gbps			UI
	1.2288 Gbps			UI
	2.4576 Gbps			UI
	3.0720 Gbps			UI
	4.9152 Gbps			UI
	6.1440 Gbps			UI
	9.8304 Gbps			UI
	10.1376 Gbps			UI
	12.16512 Gbps <sup>1</sup>			UI

1. For data rates greater than 10.3125 Gbps, VDDA must be set to 1.05 V mode. See supply tolerance in the section [Recommended Operating Conditions \(see page 6\)](#).

## 7.5.8 JESD204B

The following table describes JESD204B.

**Table 67 • JESD204B**

Parameter	Data Rate	Min	Max	Unit
Total transmit jitter	3.125 Gbps		0.35	UI
	6.25 Gbps		0.3	UI
	12.5 Gbps <sup>1</sup>			UI
Receive jitter tolerance	3.125 Gbps	0.56		UI
	6.25 Gbps	0.6		UI
	12.5 Gbps <sup>1</sup>			UI

1. For data rates greater than 10.3125 Gbps, VDDA must be set to 1.05V mode. See supply tolerance in the section [Recommended Operating Conditions \(see page 6\)](#).

## 7.6

### Non-Volatile Characteristics

The following section describes non-volatile characteristics.

## 7.6.1 FPGA Programming Cycle and Retention

The following table describes FPGA programming cycle and retention.

**Table 68 • FPGA Programming Cycles vs Retention Characteristics**

Programming T <sub>j</sub>	Programming Cycles, Max	Retention Years	Retention Years at T <sub>j</sub>
0 °C to 85 °C	1000	20	85 °C
0 °C to 100 °C	500	20	100 °C
-20 °C to 100 °C	500	20	100 °C
-40 °C to 100 °C	500	20	100 °C
-40 °C to 85 °C	1000	16	100 °C
-40 °C to 55 °C	2000	12	100 °C

**Note:** Power supplied to the device must be valid during programming operations such as programming and verify . Programming recovery mode is available only for in-application programming mode and requires an external SPI flash.

## 7.6.2 FPGA Programming Time

The following tables describe FPGA programming time.

**Table 69 • Master SPI Programming Time (IAP)**

Parameter	Symbol	Devices	Typ	Max	Unit
Programming time	T <sub>PROG</sub>	MPF100T, TL, TS, TLS			s
		MPF200T, TL, TS, TLS	17	25	s
		MPF300T, TL, TS, TLS	26	32	s
		MPF500T, TL, TS, TLS			s

**Table 70 • Slave SPI Programming Time**

Parameter	Symbol	Devices	Typ	Max	Unit
Programming time	T <sub>PROG</sub>	MPF100T, TL, TS, TLS			s
		MPF200T, TL, TS, TLS	41 <sup>1</sup>		s
		MPF300T, TL, TS, TLS	50 <sup>1</sup>	60	s
		MPF500T, TL, TS, TLS			s

1. SmartFusion2 with MSS running at 100 MHz, MSS\_SPI\_0 port running at 6.67 MHz. Bitstream stored in DDR. DirectC version 4.1.

**Table 71 • JTAG Programming Time**

Parameter	Symbol	Devices	Typ	Max	Unit
Programming time	T <sub>PROG</sub>	MPF100T, TL, TS, TLS			s
		MPF200T, TL, TS, TLS	56		s
		MPF300T, TL, TS, TLS <sup>1</sup>	95		s
		MPF500T, TL, TS, TLS			s

1. Programmer: FlashPro5 with TCK 10 MHz. PC Configuration: Intel i7 at 3.6 GHz, 32 GB RAM, Windows 10.

**Table 75 • FPGA Programming Cycles Lifetime Factor**

Programming T <sub>j</sub>	Programming Cycles	LF
-40 °C to 100 °C	500	1
-40 °C to 85 °C	1000	0.8
-40 °C to 55 °C	2000	0.6

**Notes:**

- The maximum number of device digest cycles is 100K.
- Digests are operational only over the -40 °C to 100 °C temperature range.
- After a program cycle, an additional N digest cycles are allowed with the resultant retention characteristics for the total operating and storage temperature shown.
- Retention is specified for total device storage and operating temperature.
- All temperatures are junction temperatures (T<sub>j</sub>).
- Example 1—500 digest cycles are performed between programming cycles. N = 500. The operating conditions are -40 °C to 85 °C T<sub>j</sub>. 501 programming cycles have occurred. The retention under these operating conditions is  $20 \times LF = 20 \times .8 = 16$  years.
- Example 2—one programming cycle has occurred, N = 1500 digest cycles have occurred. Temperature range is -40 °C to 100 °C. The resultant retention is  $10 \times LF$  or 10 years over the industrial temperature range.

**7.6.5 Digest Time**

The following table describes digest time.

**Table 76 • Digest Times**

Parameter	Devices	Typ	Max	Unit
Setup time	All	2		μs
Fabric digest run time	MPF100T, TL, TS, TLS			ms
	MPF200T, TL, TS, TLS	1005	1072	ms
	MPF300T, TL, TS, TLS	1503.9	1582	ms
	MPF500T, TL, TS, TLS			ms
UFS CC digest run time	MPF100T, TL, TS, TLS			μs
	MPF200T, TL, TS, TLS	33.2	35	μs
	MPF300T, TL, TS, TLS	33.2	35	μs
	MPF500T, TL, TS, TLS			μs
sNVM digest run time <sup>1</sup>	MPF100T, TL, TS, TLS			ms
	MPF200T, TL, TS, TLS	4.4	4.8	ms
	MPF300T, TL, TS, TLS	4.4	4.8	ms
	MPF500T, TL, TS, TLS			ms
UFS UL digest run time	MPF100T, TL, TS, TLS			μs
	MPF200T, TL, TS, TLS	46.6	48.8	μs
	MPF300T, TL, TS, TLS	46.6	48.8	μs
	MPF500T, TL, TS, TLS			μs
User key digest run time <sup>2</sup>	MPF100T, TL, TS, TLS			μs
	MPF200T, TL, TS, TLS	525.4	543.3	μs
	MPF300T, TL, TS, TLS	525.4	543.3	μs
	MPF500T, TL, TS, TLS			μs

Parameter	Type	Max	Unit	Conditions
Time to destroy data in non-volatile memory (non-recoverable) <sup>1,4</sup>		ms		One iteration of scrubbing
Time to scrub the fabric data <sup>1</sup>		s		Full scrubbing
Time to scrub the pNVM data (like new) <sup>1,2</sup>		s		Full scrubbing
Time to scrub the pNVM data (recoverable) <sup>1,3</sup>		s		Full scrubbing
Time to scrub the fabric data pNVM data (non-recoverable) <sup>1</sup>		s		Full scrubbing
Time to verify <sup>5</sup>		s		

1. Total completion time after entering zeroization.
2. Like new mode—zeroizes user design security setting and sNVM content.
3. Recoverable mode—zeroizes user design security setting, sNVM and factory keys.
4. Non-recoverable mode—zeroizes user design security setting, sNVM and factory keys, and factory data required for programming.
5. Time to verify after scrubbing completes.

## 7.6.7 Verify Time

The following tables describe verify time.

**Table 81 • Standalone Fabric Verify Times**

Parameter	Devices	Max	Unit
Standalone verification over JTAG	MPF100T, TL, TS, TLS		s
	MPF200T, TL, TS, TLS	53 <sup>1</sup>	s
	MPF300T, TL, TS, TLS	90 <sup>1</sup>	s
	MPF500T, TL, TS, TLS		s
Standalone verification over SPI	MPF100T, TL, TS, TLS		s
	MPF200T, TL, TS, TLS	37 <sup>2</sup>	s
	MPF300T, TL, TS, TLS	55 <sup>2</sup>	s
	MPF500T, TL, TS, TLS		s

1. Programmer: FlashPro5, TCK 10 MHz; PC configuration: Intel i7 at 3.6 GHz, 32 GB RAM, Windows 10.
2. SmartFusion2 with MSS running at 100 MHz, MSS\_SPI\_0 port running at 6.67 MHz. DirectC version 4.1.

**Notes:**

- Standalone verify is limited to 2,000 total device hours over the industrial –40 °C to 100 °C temperature.
- Use the digest system service, for verify device time more than 2,000 hours.
- Standalone verify checks the programming margin on both the P and N gates of the push-pull cell.
- Digest checks only the P side of the push-pull gate. However, the push-pull gates work in tandem. Digest check is recommended if users believe they will exceed the 2,000-hour verify time specification.

**Table 82 • Verify Time by Programming Hardware**

Devices	IAP	FlashPro4	FlashPro5	BP	Silicon Sculptor	Units
MPF100T, TL, TS, TLS						
MPF200T, TL, TS, TLS	9	67	53			s
MPF300T, TL, TS, TLS	14	95	90			s

Parameter	Symbol	Typ	Max	Unit
Time from negation of RESPONSE to all I/Os re-enabled	T <sub>CLR_IO_DISABLE</sub>	28	38	μs
Time from triggering the response to security locked	T <sub>LOCKDOWN</sub>			ns
Time from negation of RESPONSE to earlier security unlock condition	T <sub>CLR_LOCKDOWN</sub>			ns
Time from triggering the response to device enters RESET	T <sub>tr_RESET</sub>	11.7	14	μs
Time from triggering the response to start of zeroization	T <sub>tr_ZEROISE</sub>	7.4	8.2	ms

## 7.8.5 System Controller Suspend Switching Characteristics

The following table describes the characteristics of system controller suspend switching.

**Table 95 • System Controller Suspend Entry and Exit Characteristics**

Parameter	Symbol	Definition	Typ	Max	Unit
Time from TRSTb falling edge to SUSPEND_EN signal assertion	T <sub>suspend_Tr</sub> <sup>1, 2</sup>	Suspend entry time from TRST_N assertion	42	44	ns
Time from TRSTb rising edge to ACTIVE signal assertion	T <sub>suspend_exit</sub>	Suspend exit time from TRST_N negation	361	372	ns

1. ACTIVE indicates that the system controller is inactive or active regardless of the state of SUSPEND\_EN.
2. ACTIVE signal must never be asserted with SUSPEND\_EN is asserted.

## 7.8.6 Dynamic Reconfiguration Interface

The following table provides interface timing information for the DRI, which is an embedded APB slave interface within the FPGA fabric that does not use FPGA resources.

**Table 96 • Dynamic Reconfiguration Interface Timing Characteristics**

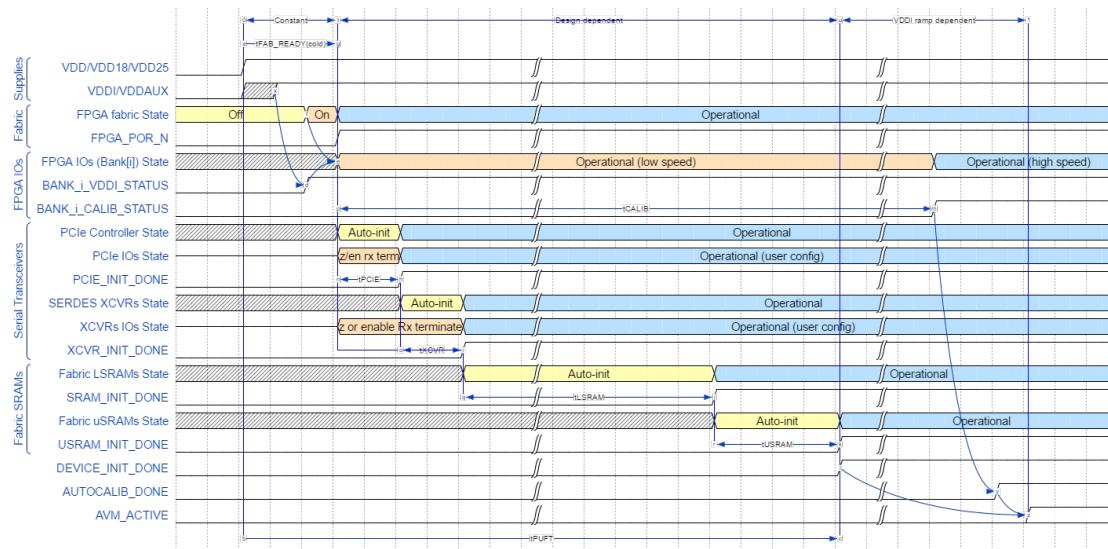
Parameter	Symbol	Max	Unit
PCLK frequency	F <sub>PD_PCLK</sub>	200	MHz

## 7.9 Power-Up to Functional Timing

Microsemi non-volatile FPGA technology offers the fastest boot-time of any mid-range FPGA in the market. The following tables describes both cold-boot (from power-on) and warm-boot (assertion of DEVRST\_N pin or assertion of reset from the tamper macro) timing. The power-up diagrams assume all power supplies to the device are stable.

### 7.9.1 Power-On (Cold) Reset Initialization Sequence

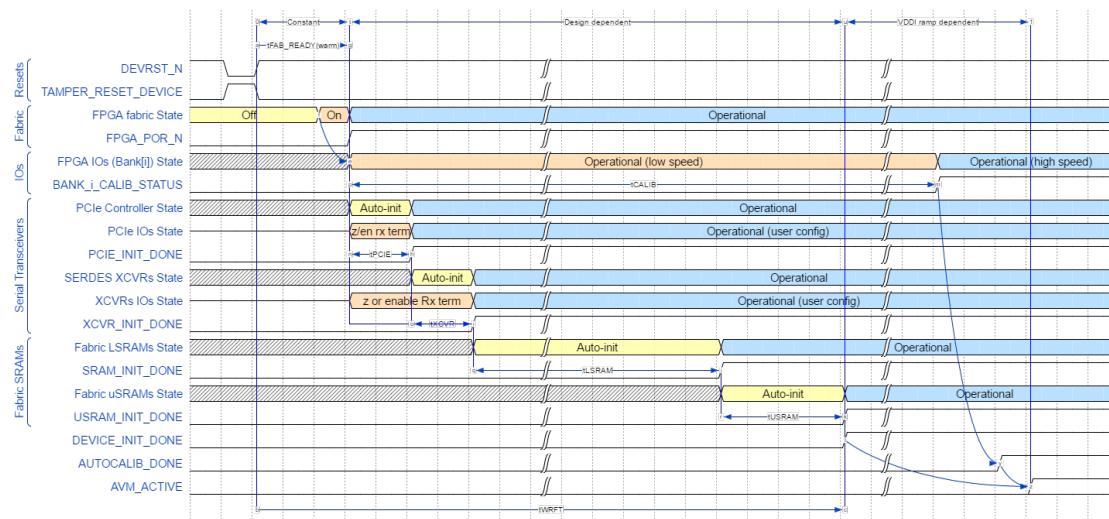
The following cold reset timing diagram shows the initialization sequencing of the device.

**Figure 5 • Cold Reset Timing****Notes:**

- The previous diagram shows the case where VDDI/VDDAUX of I/O banks are powered either before or sufficiently soon after VDD/VDD18/VDD25 that the I/O bank enable time is measured from the assertion time of VDD/VDD18/VDD25 (that is, the PUFT specification). If VDDI/VDDAUX of I/O banks are powered sufficiently after VDD/VDD18/VDD25, then the I/O bank enable time is measured from the assertion of VDDI/VDDAUX and is not specified by the PUFT specification. In this case, I/O operation is indicated by the assertion of BANK\_i\_VDDI\_STATUS, rather than being measured relative to FABRIC\_POR\_N negation.
- AUTOCALIB\_DONE assertion indicates the completion of calibration for any I/O banks specified by the user for auto-calibration. AUTOCALIB\_DONE asserts independently of DEVICE\_INIT\_DONE. It may assert before or after DEVICE\_INIT\_DONE and is determined by the following:
  - How long after VDD/VDD18/VDD25 that VDDI/VDDAUX are powered on. Note that if any of the user-specified I/O banks are not powered on within the auto-calibration timeout window, then AUTOCALIB\_DONE doesn't assert until after this timeout.
  - The specified ramp times of VDDI of each I/O bank designated for auto-calibration.
  - How much auto-initialization is to be performed for the PCIe, SERDES transceivers, and fabric LSRAMs.
  - If any of the I/O banks specified for auto-calibration do not have their VDDI/VDDAUX powered on within the auto-calibration timeout window, then it will be approximately auto-calibrated whenever VDDI/VDDAUX is subsequently powered on. To obtain an accurate calibration however, on such IO banks, it is necessary to initiate a re-calibration (using CALIB\_START from fabric).
  - AVM\_ACTIVE only asserts if avionics mode is being used. It is asserted when the later of DEVICE\_INIT\_DONE or AUTOCALIB\_DONE assert.

**7.9.2****Warm Reset Initialization Sequence**

The following warm reset timing diagram shows the initialization sequencing of the device when either DEVRST\_N or TAMPER\_RESET\_DEVICE signals are asserted.

**Figure 6 • Warm Reset Timing**

## 7.9.3 Power-On Reset Voltages

### 7.9.3.1 Main Supplies

The start of power-up to functional time ( $T_{PUFT}$ ) is defined as the point at which the latest of the main supplies (VDD, VDD18, VDD25) reach the reference voltage levels specified in the following table. This starts the process of releasing the reset of the device and powering on the FPGA fabric and IOs.

**Table 97 • POR Ref Voltages**

Supply	Power-On Reset Start Point (V)	Note
VDD	0.95	Applies to both 1.0 V and 1.05 V operation.
VDD18	1.71	
VDD25	2.25	

### 7.9.3.2 I/O-Related Supplies

For the I/Os to become functional (for low speed, sub 400 MHz operation), the (per-bank) I/O supplies (VDDI, VDDAUX) must reach the trip point voltage levels specified in the following table and the main supplies above must also be powered on.

**Table 98 • I/O-Related Supplies**

Supply	I/O Power-Up Start Point (V)
VDDI	0.85
VDDAUX	1.6

There are no sequencing requirements for the power supplies. However, VDDI3 must be valid at the same time as the main supplies. The other IO supplies (VDDI, VDDAUX) have no effect on power-up of FPGA fabric (that is, the fabric still powers up even if the IO supplies of some IO banks remain powered off).

**Table 107 • SPI Master Mode (PolarFire Master) During Device Initialization**

Parameter	Symbol	Min	Typ	Max	Unit	Condition
SCK frequency	F <sub>M</sub> SCK			40	MHz	

**Table 108 • SPI Slave Mode (PolarFire Slave)**

Parameter	Symbol	Min	Typ	Max	Unit	Condition
SCK frequency	F <sub>S</sub> SCK			80	MHz	

### 7.10.3 SmartDebug Probe Switching Characteristics

The following table describes characteristics of SmartDebug probe switching.

**Table 109 • SmartDebug Probe Performance Characteristics**

Parameter	Symbol	V <sub>DD</sub> = 1.0 V STD	V <sub>DD</sub> = 1.0 V – 1	V <sub>DD</sub> = 1.05 V STD	V <sub>DD</sub> = 1.05 V – 1	Unit
Maximum frequency of probe signal	F <sub>MAX</sub>	100	100	100	100	MHz
Minimum delay of probe signal	T <sub>Min_delay</sub>	13	12	13	12	ns
Maximum delay of probe signal	T <sub>Max_delay</sub>	13	12	13	12	ns

### 7.10.4 DEVRST\_N Switching Characteristics

The following table describes characteristics of DEVRST\_N switching.

**Table 110 • DEVRST\_N Electrical Characteristics**

Parameter	Symbol	Min	Typ	Max	Unit	Condition
DEVRST_N ramp rate	DR <sub>RAMP</sub>		10		μs	It must be a normal clean digital signal, with typical rise and fall times
DEVRST_N assert time	DR <sub>ASSERT</sub>	1			μs	The minimum time for DEVRST_N assertion to be recognized
DEVRST_N de-assert time	DR <sub>DEASSERT</sub>		2.75		ms	The minimum time DEVRST_N needs to be de-asserted before assertion

### 7.10.5 FF\_EXIT Switching Characteristics

The following table describes characteristics of FF\_EXIT switching.

**Table 111 • FF\_EXIT Electrical Characteristics**

Parameter	Symbol	Min	Typ	Max	Unit	Condition
FF_EXIT_N ramp rate	FF <sub>RAMP</sub>		10		μs	
Minimum FF_EXIT_N assert time	FF <sub>ASSERT</sub>	1			μs	The minimum time for FF_EXIT_N to be recognized
Minimum FF_EXIT_N de-assert time	FF <sub>DEASSERT</sub>	170			μs	The minimum time FF_EXIT_N needs to be de-asserted before assertion